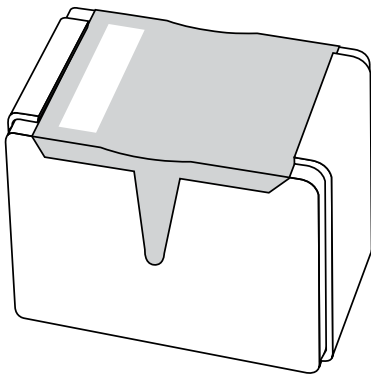


DATA SHEET



BAS216

High-speed switching diode

Product data sheet
Supersedes data of 1999 Apr 22

2002 May 28

High-speed switching diode

BAS216

FEATURES

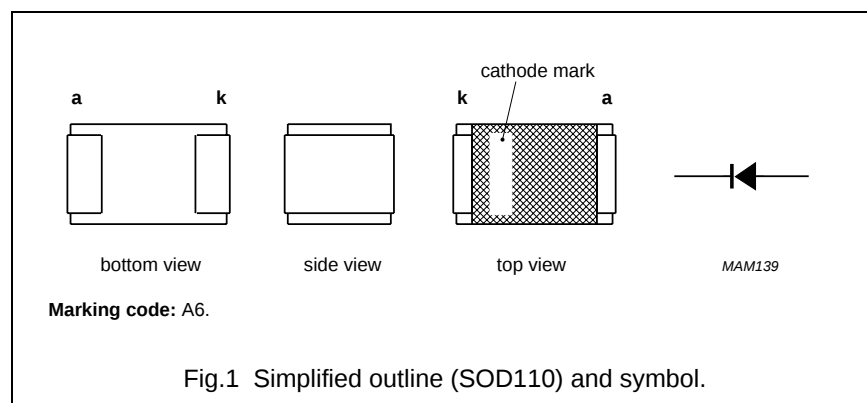
- Small ceramic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

APPLICATIONS

- High-speed switching in e.g. surface mounted circuits.

DESCRIPTION

The BAS216 is a high-speed switching diode fabricated in planar technology, and encapsulated in the SOD110 very small rectangular ceramic SMD package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage		–	85	V
V_R	continuous reverse voltage		–	75	V
I_F	continuous forward current	note 1	–	250	mA
I_{FRM}	repetitive peak forward current		–	500	mA
I_{FSM}	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\text{ }\mu\text{s}$ $t = 1\text{ ms}$ $t = 1\text{ s}$	– – –	4 1 0.5	A A A
P_{tot}	total power dissipation	$T_{amb} = 25\text{ °C}$; see Fig.2; note 1	–	400	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.

High-speed switching diode

BAS216

ELECTRICAL CHARACTERISTICST_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	see Fig.3 I _F = 1 mA I _F = 10 mA I _F = 50 mA I _F = 150 mA	– – – –	715 855 1 1.25	mV mV V V
I _R	reverse current	see Fig.5 V _R = 25 V V _R = 75 V V _R = 25 V; T _j = 150 °C V _R = 75 V; T _j = 150 °C	– – – –	30 1 30 50	nA μA μA μA
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	–	1.5	pF
t _{rr}	reverse recovery time	when switched from I _F = 10 mA to I _R = 10 mA; R _L = 100 Ω; measured at I _R = 1 mA; see Fig.7	–	4	ns
V _{fr}	forward recovery voltage	when switched from I _F = 10 mA; t _r = 20 ns; see Fig.8	–	1.75	V

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		200	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	315	K/W

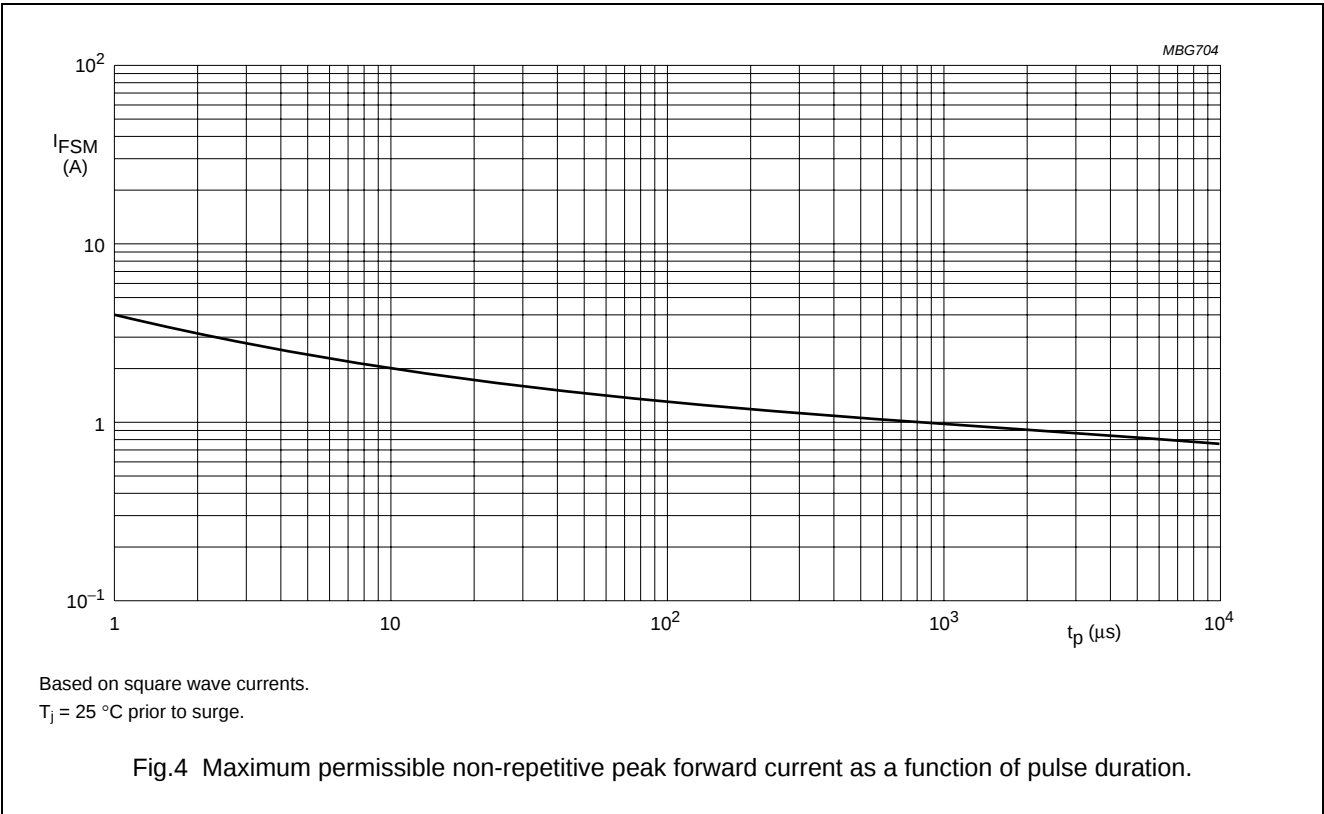
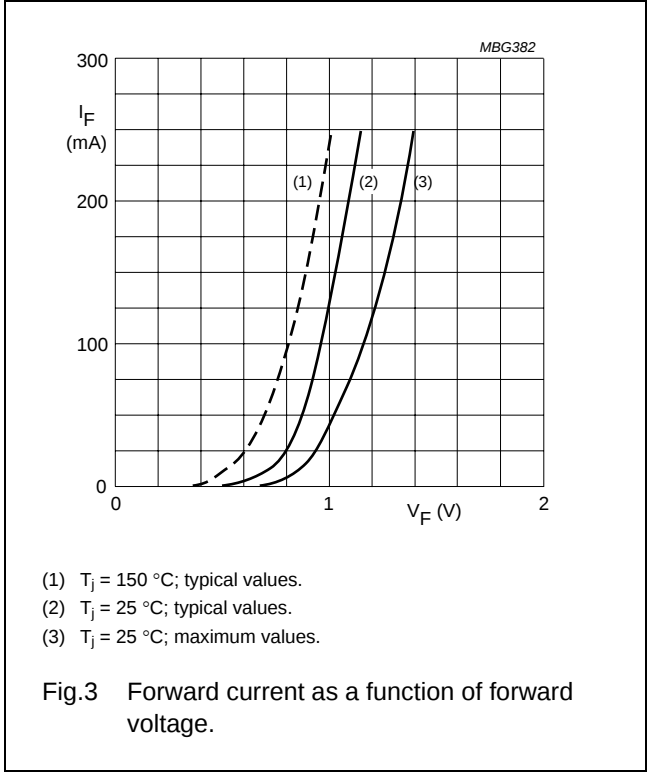
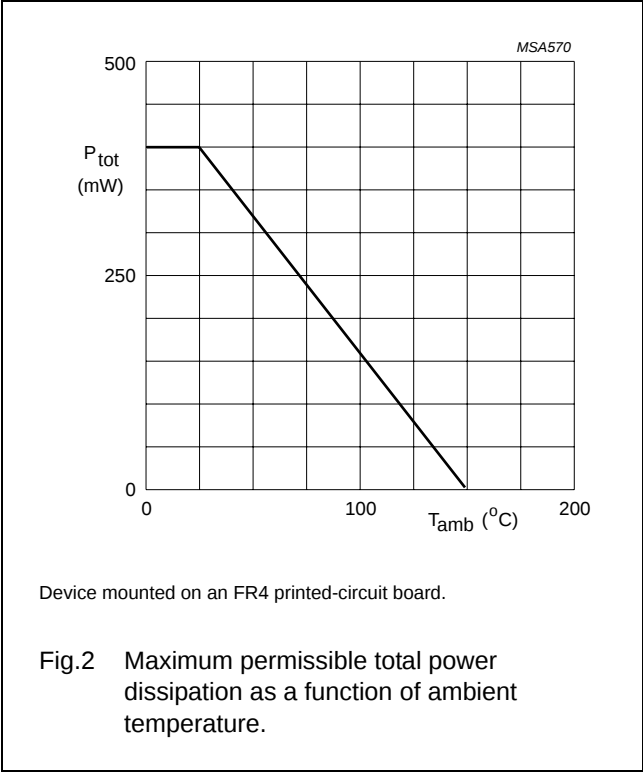
Note

1. Device mounted on an FR4 printed-circuit board.

High-speed switching diode

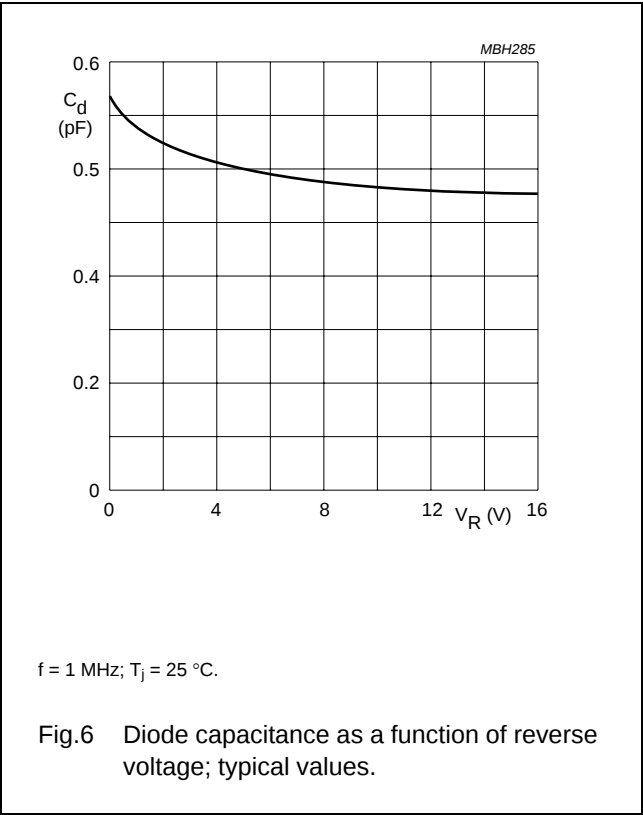
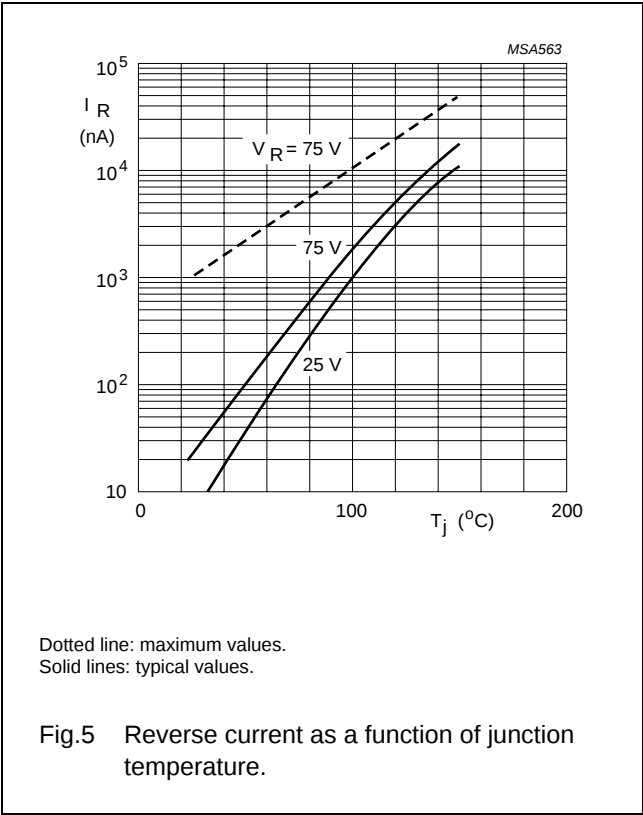
BAS216

GRAPHICAL DATA



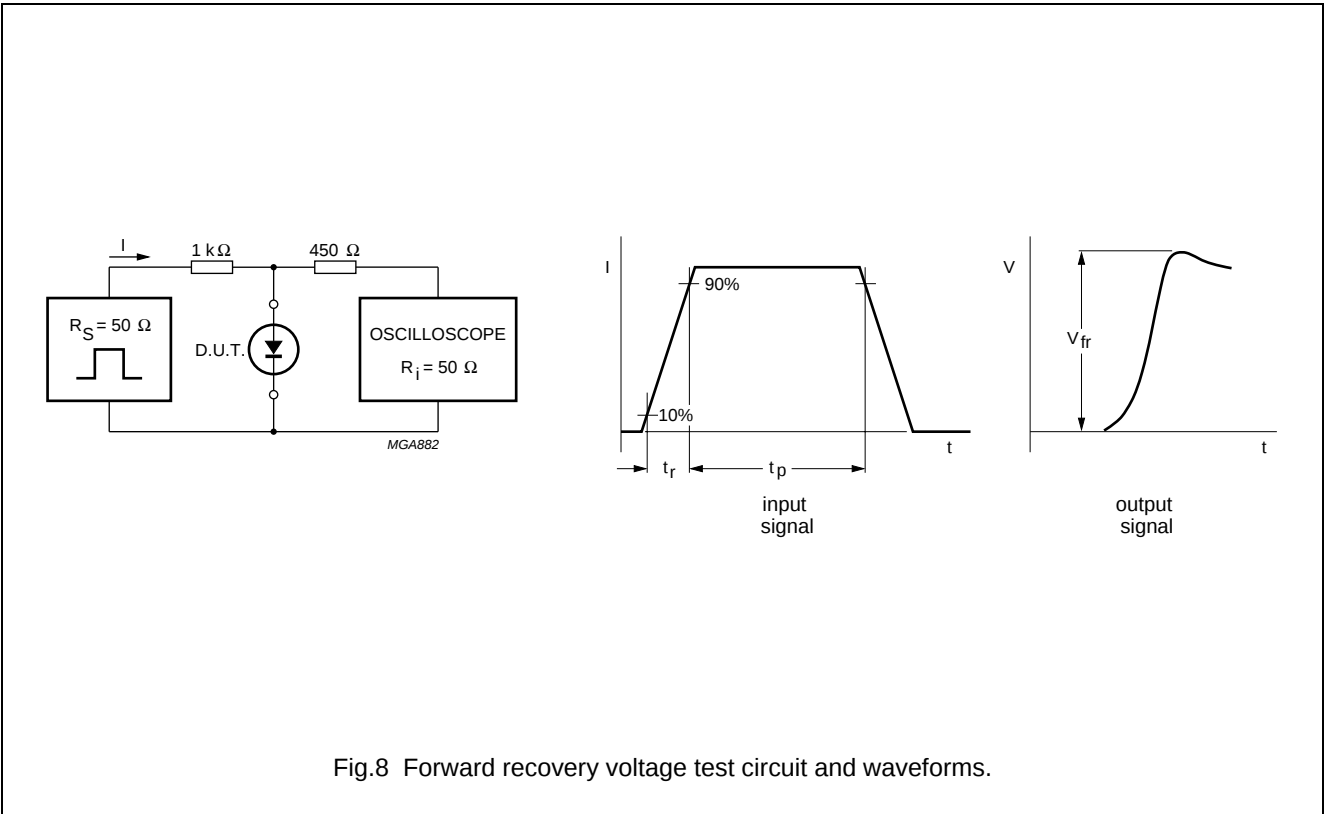
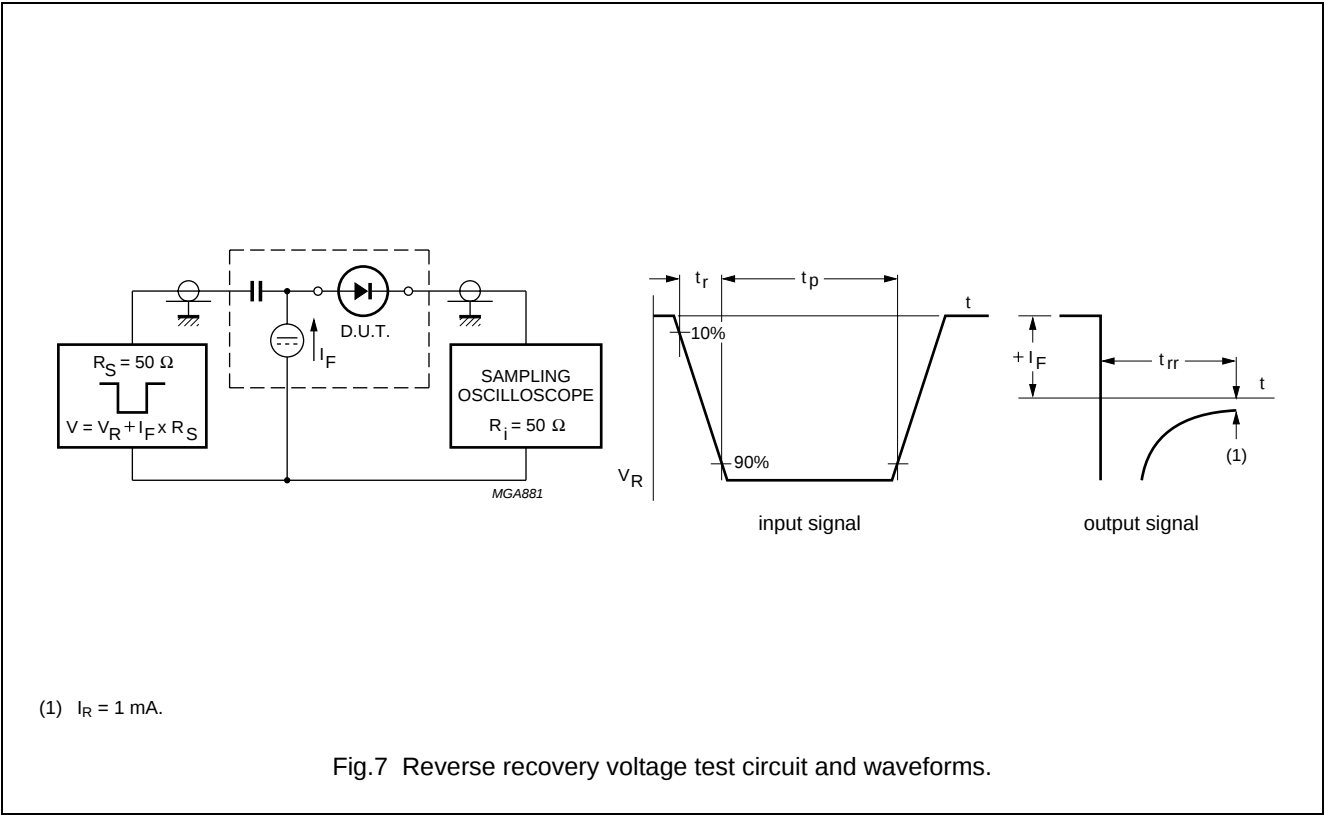
High-speed switching diode

BAS216



High-speed switching diode

BAS216



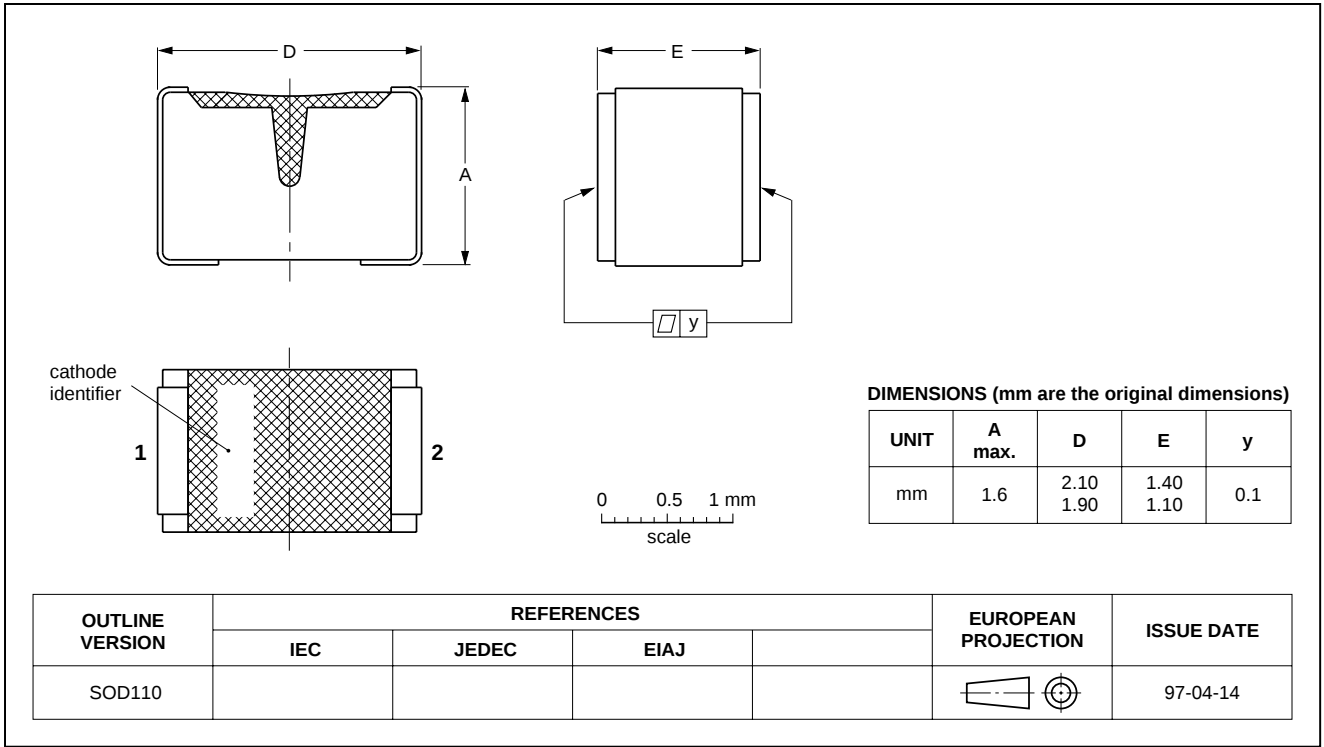
High-speed switching diode

BAS216

PACKAGE OUTLINE

Very small ceramic rectangular surface mounted package

SOD110



High-speed switching diode

BAS216

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.